



• Dynamic Ratings

Parameter	Symbol	Conditions	min.	typ.	max.	Unit
Forward Transconductance	$g_{fs}$	$I_D=23.5A$ $V_{DS}=25V$	17	35	-	S
Input Capacitance	$C_{iss}$	$V_{DS}=400V$	-	3600	-	pF
Output Capacitance	$C_{oss}$	$V_{GS}=0V$	-	105	-	
Reverse Transfer Capacitance	$C_{rss}$	$f=250kHz$	-	7.5	-	
Effective output capacitance, energy related (Note *6)	$C_{o(er)}$	$V_{GS}=0V$ $V_{DS}=0...400V$	-	275	-	
Effective output capacitance, time related (Note *7)	$C_{o(tr)}$	$V_{GS}=0V$ $V_{DS}=0...400V$ $I_D=constant$	-	945	-	
Turn-On Time	$t_{d(on)}$ $t_r$	$V_{DD}=400V, V_{GS}=10V$ $I_D=23.5A, R_G=13\Omega$ See Fig.3 and Fig.4	-	146	-	ns
Turn-Off Time	$t_{d(off)}$ $t_f$		-	32	-	
Total Gate Charge	$Q_G$	$V_{DD}=400V, I_D=47A$ $V_{GS}=10V$ See Fig.5	-	127	-	nC
Gate-Source Charge	$Q_{GS}$		-	33	-	
Gate-Drain Charge	$Q_{GD}$		-	55	-	
Drain-Source crossover Charge	$Q_{SW}$		-	16	-	

Note \*6 :  $C_{o(er)}$  is a fixed capacitance that gives the same stored energy as  $C_{oss}$  while  $V_{DS}$  is rising from 0 to 400V.

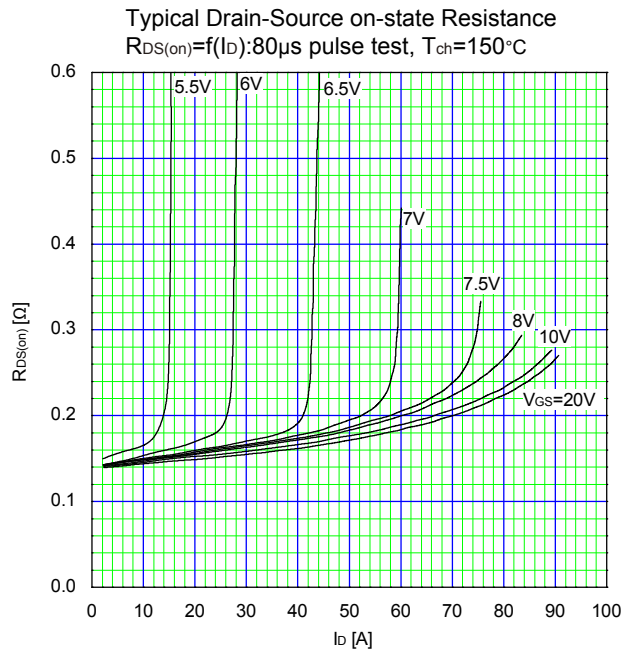
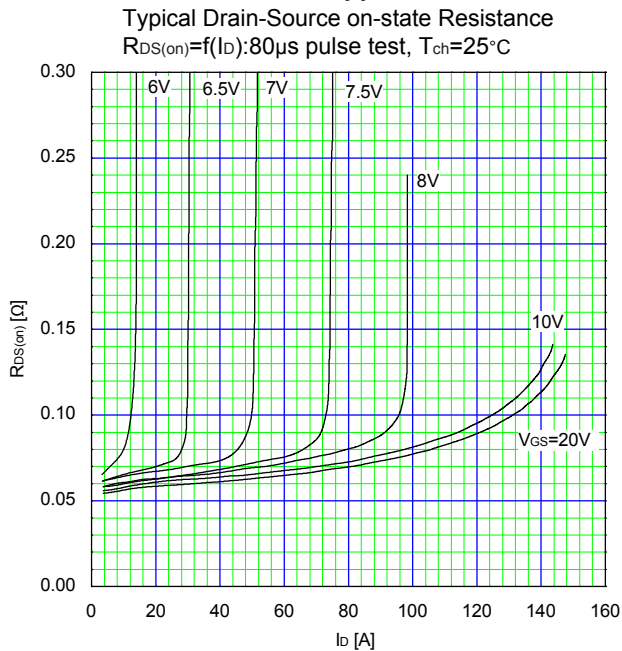
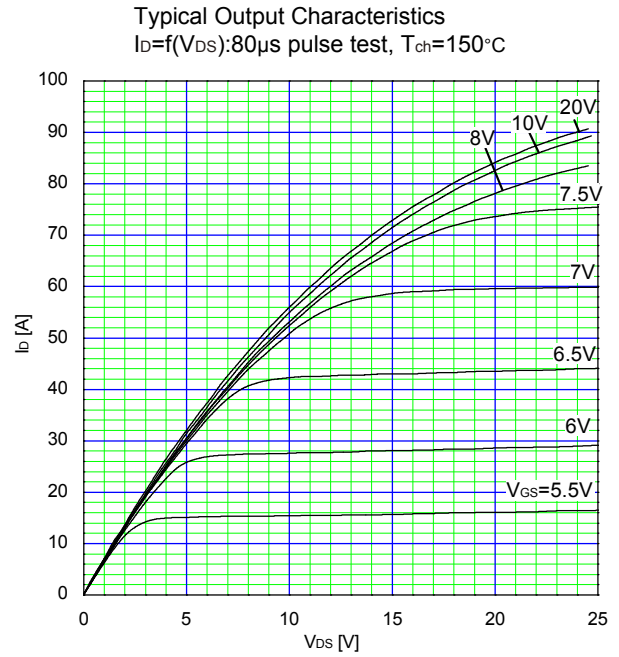
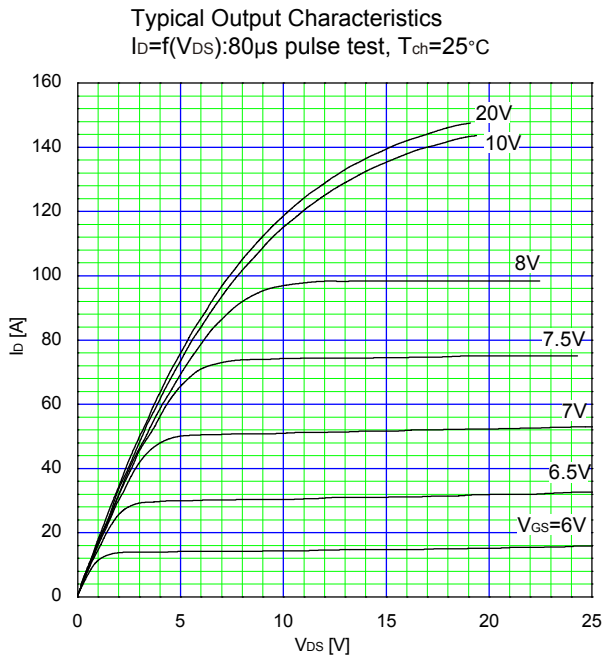
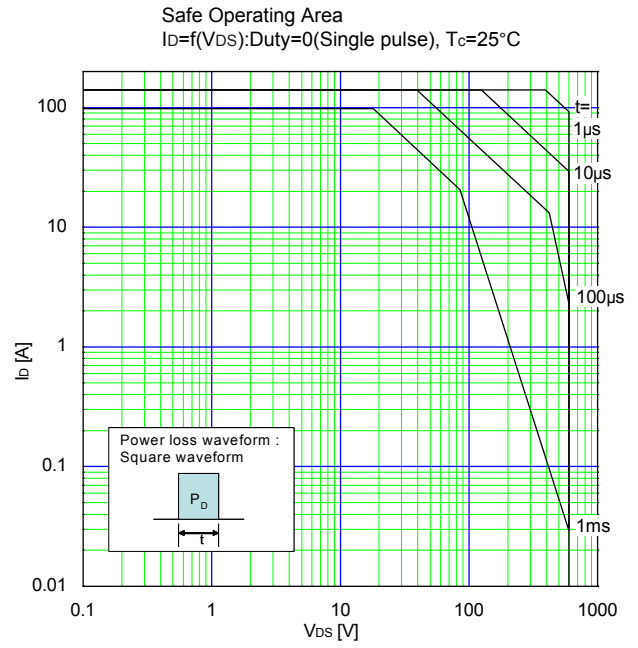
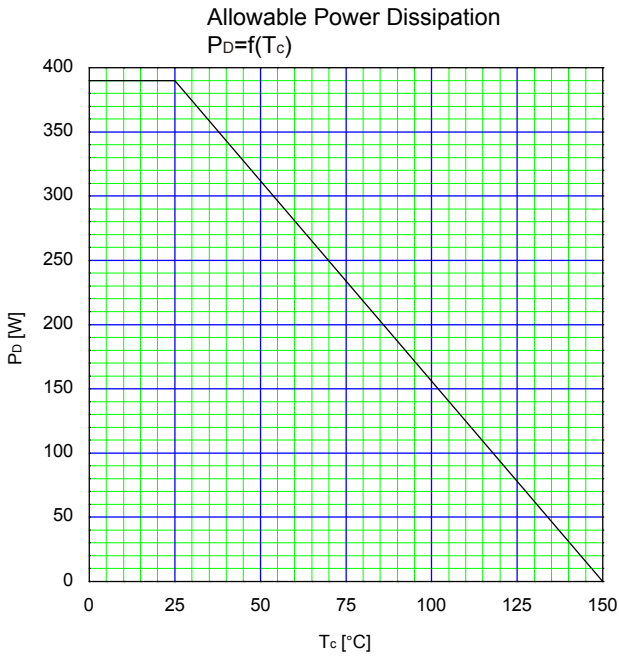
Note \*7 :  $C_{o(tr)}$  is a fixed capacitance that gives the same charging times as  $C_{oss}$  while  $V_{DS}$  is rising from 0 to 400V.

• Reverse Diode

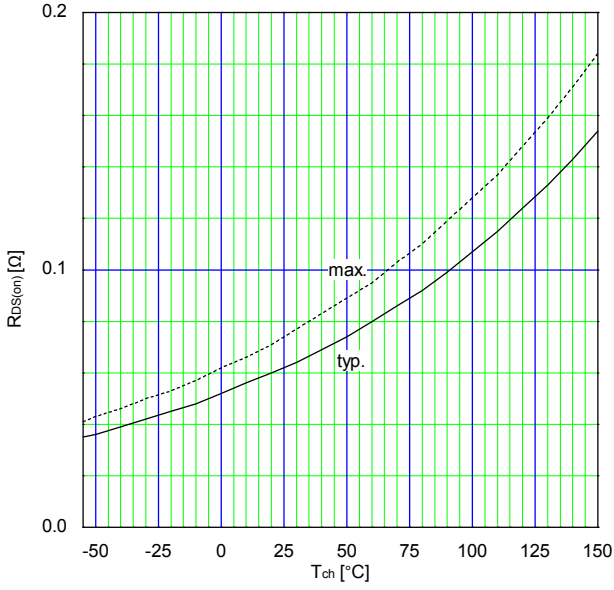
Parameter	Symbol	Conditions	min.	typ.	max.	Unit
Avalanche Capability	$I_{AV}$	$L=20.6mH, T_{ch}=25^\circ C$ See Fig.1 and Fig.2	9.5	-	-	A
Diode Forward On-Voltage	$V_{SD}$	$I_F=47A, V_{GS}=0V$ $T_{ch}=25^\circ C$	-	1.1	1.35	V
Reverse Recovery Time	$t_{rr}$	$I_F=47A, V_{DD}=400V$ $-di/dt=100A/\mu s$ $T_{ch}=25^\circ C$ See Fig.6 and Fig.7	-	210	-	ns
Reverse Recovery Charge	$Q_{rr}$		-	1.6	-	$\mu C$
Peak Reverse Recovery Current	$I_{rp}$		-	15	-	A

■ Thermal Resistance

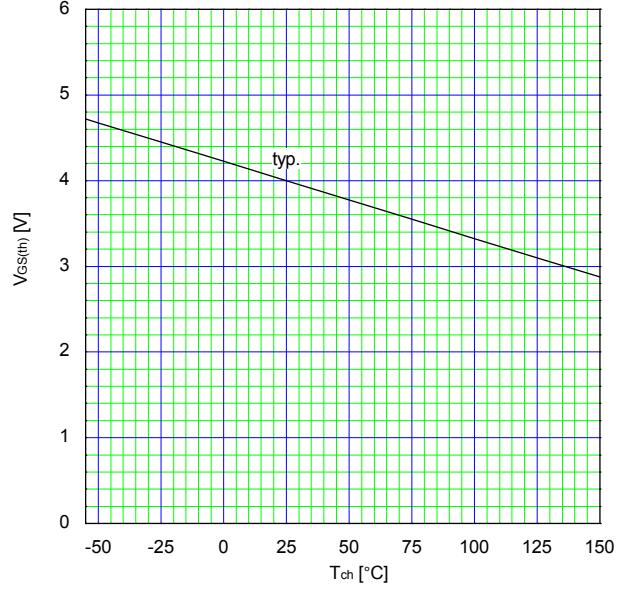
Parameter	Symbol	min.	typ.	max.	Unit
Channel to Case	$R_{th(ch-c)}$	-	-	0.32	$^\circ C/W$
Channel to Ambient	$R_{th(ch-a)}$	-	-	50	$^\circ C/W$



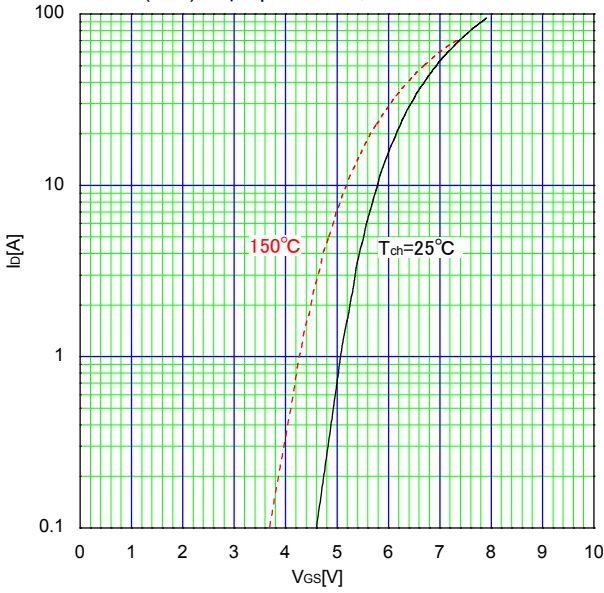
Drain-Source On-state Resistance  
 $R_{DS(on)}=f(T_{ch}): I_D=23.5A, V_{GS}=10V$



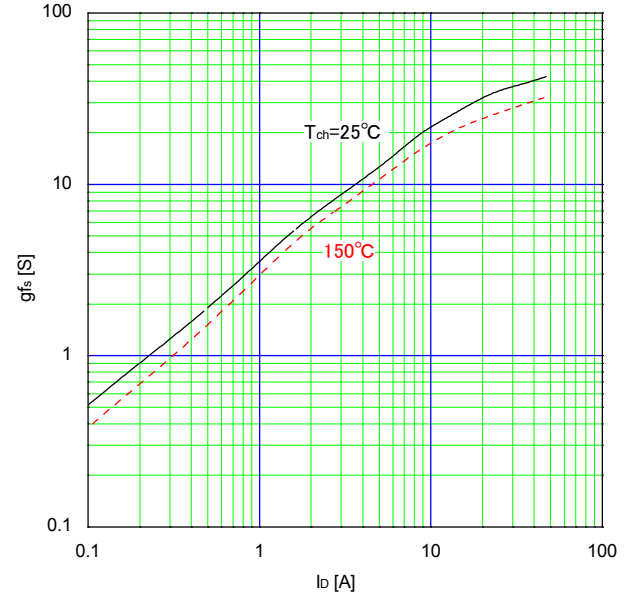
Gate Threshold Voltage vs.  $T_{ch}$   
 $V_{GS(th)}=f(T_{ch}): V_{DS}=V_{GS}, I_D=2mA$



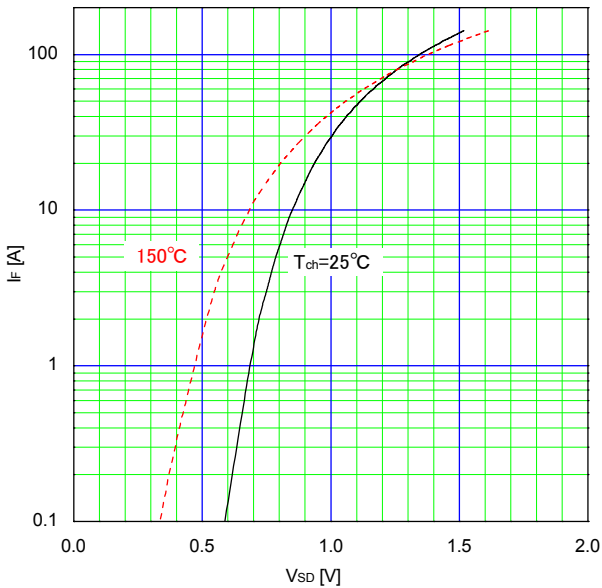
Typical Transfer Characteristic  
 $I_D=f(V_{GS}): 80\mu s$  pulse test,  $V_{DS}=25V$



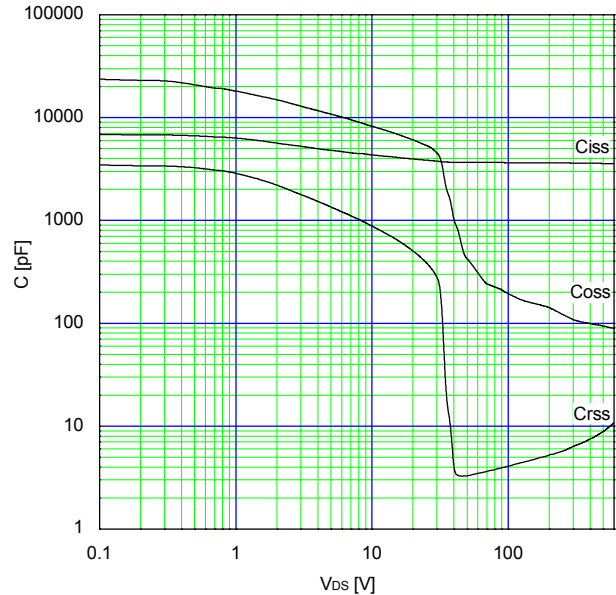
Typical Transconductance  
 $g_{fs}=f(I_D): 80\mu s$  pulse test,  $V_{DS}=25V$



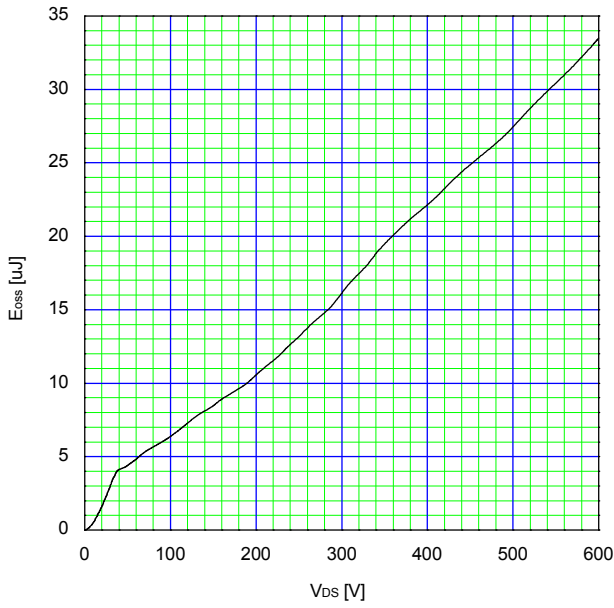
Typical Forward Characteristics of Reverse Diode  
 $I_F=f(V_{SD}): 80\mu s$  pulse test



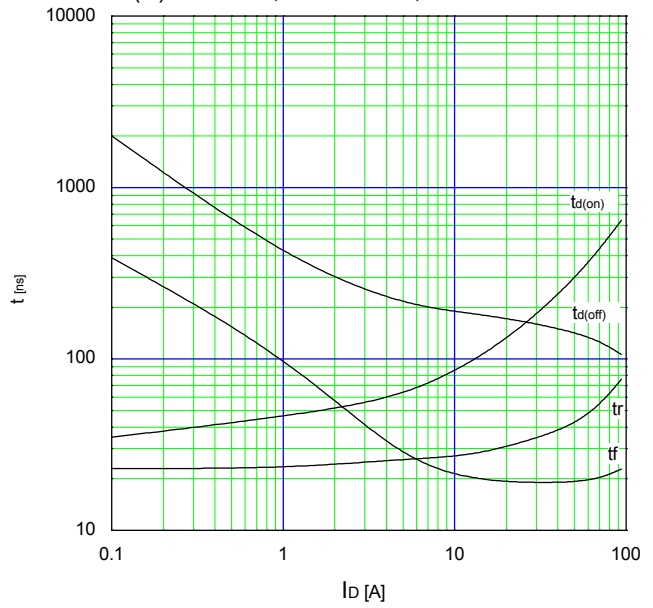
Typical Capacitance  
 $C=f(V_{DS}): V_{GS}=0V, f=250kHz$



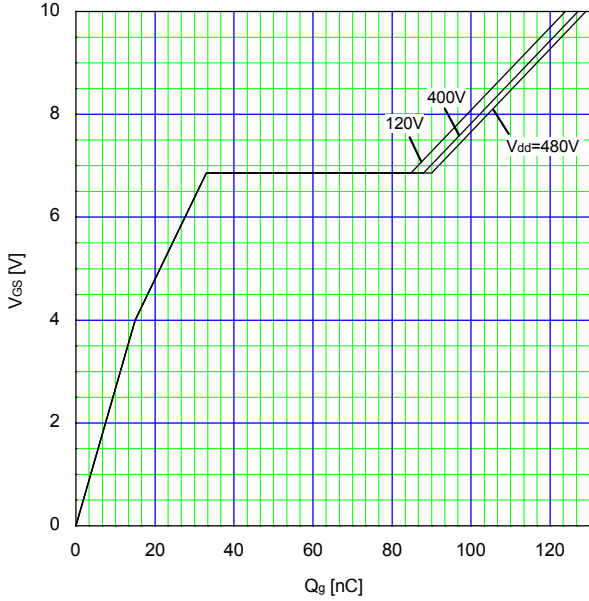
Typical Coss stored energy



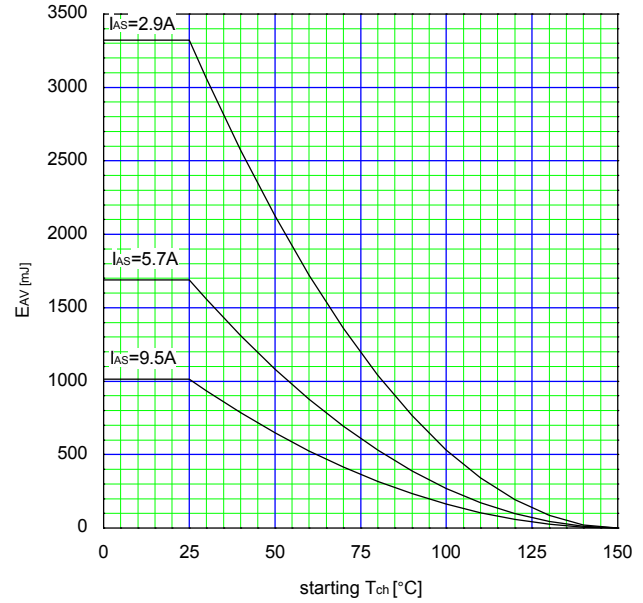
Typical Switching Characteristics vs. ID Tch=25°C  
t=f(ID):V<sub>dd</sub>=400V, V<sub>GS</sub>=10V/0V, R<sub>G</sub>=13Ω



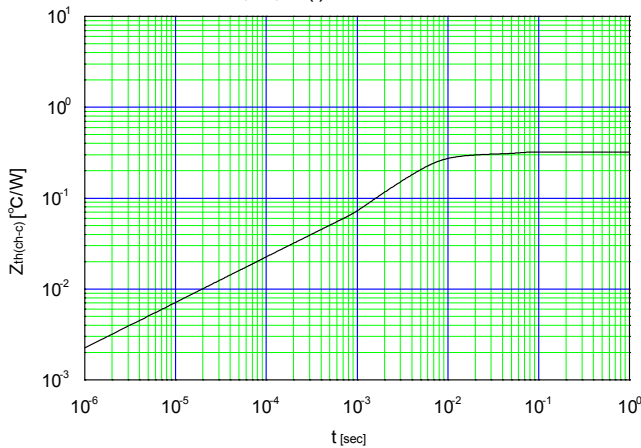
Typical Gate Charge Characteristics  
V<sub>GS</sub>=f(Q<sub>g</sub>):ID=47A, Tch=25°C



Maximum Avalanche Energy vs. starting Tch  
E<sub>(AV)</sub>=f(starting Tch):V<sub>CC</sub>=60V, I<sub>(AV)</sub><=9.5A



Transient Thermal Impedance  
Z<sub>th(ch-c)}</sub>=f(t):D=0



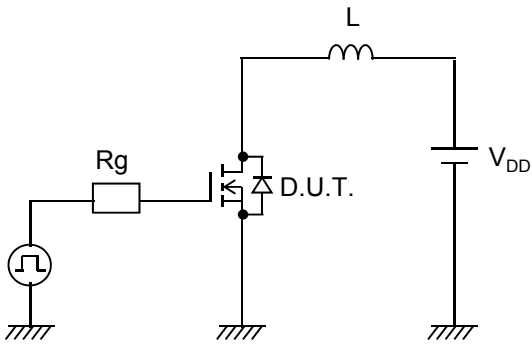


Fig.1 Avalanche Test circuit

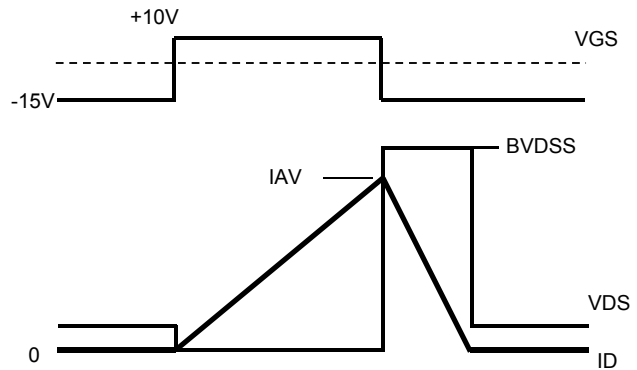


Fig.2 Operating waveforms of Avalanche Test

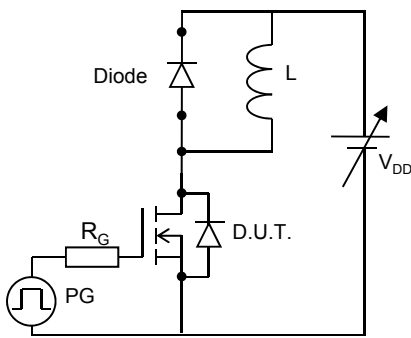


Fig.3 Switching Test circuit

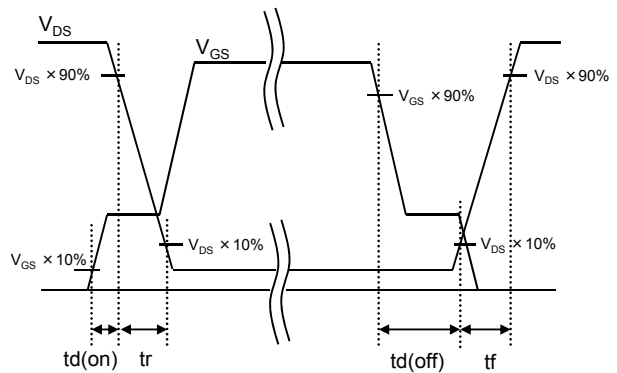


Fig.4 Operating waveform of Switching Test

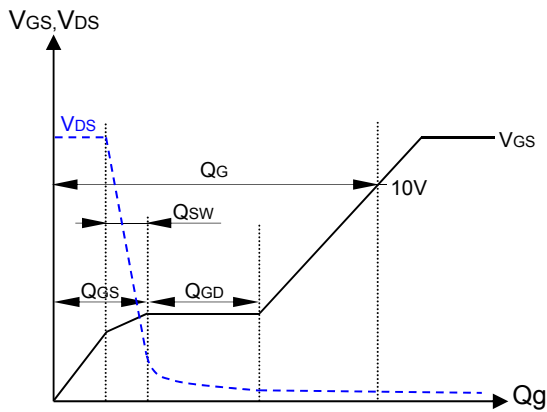


Fig.5 Operating waveform of Gate charge Test

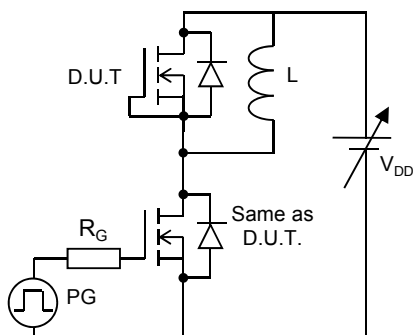


Fig.6 Reverse recovery Test circuit

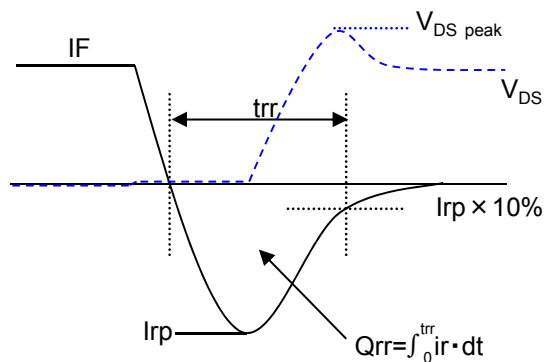
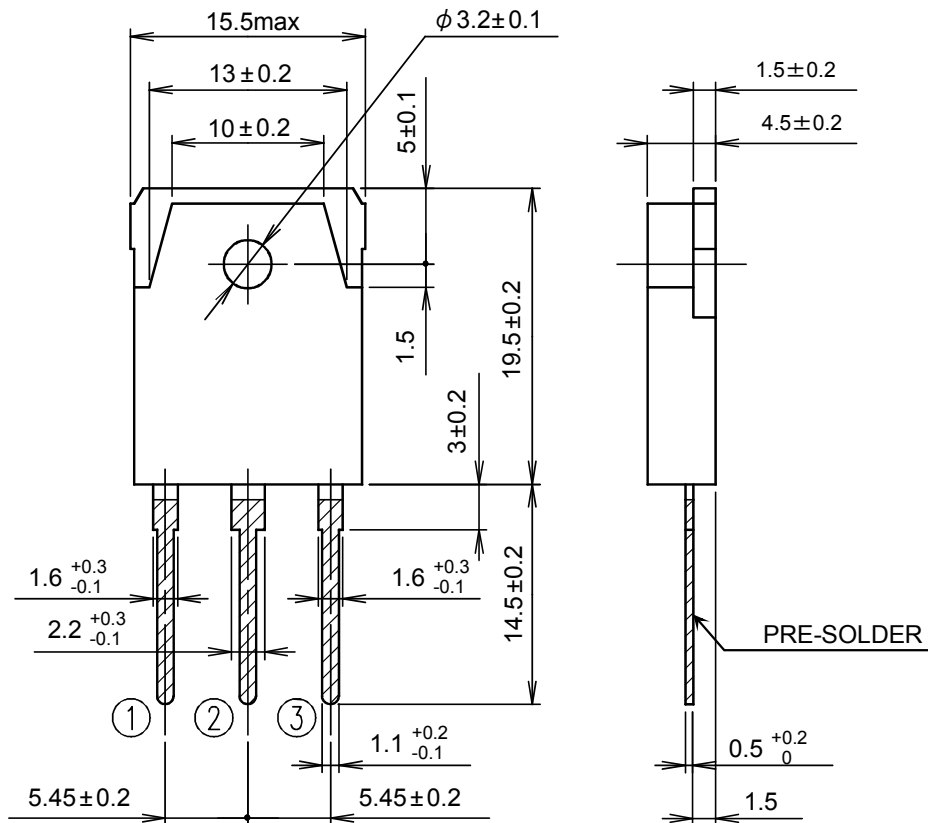
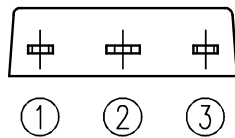


Fig.7 Operating waveform of Reverse recovery Test

■ Outview: TO-3P Package



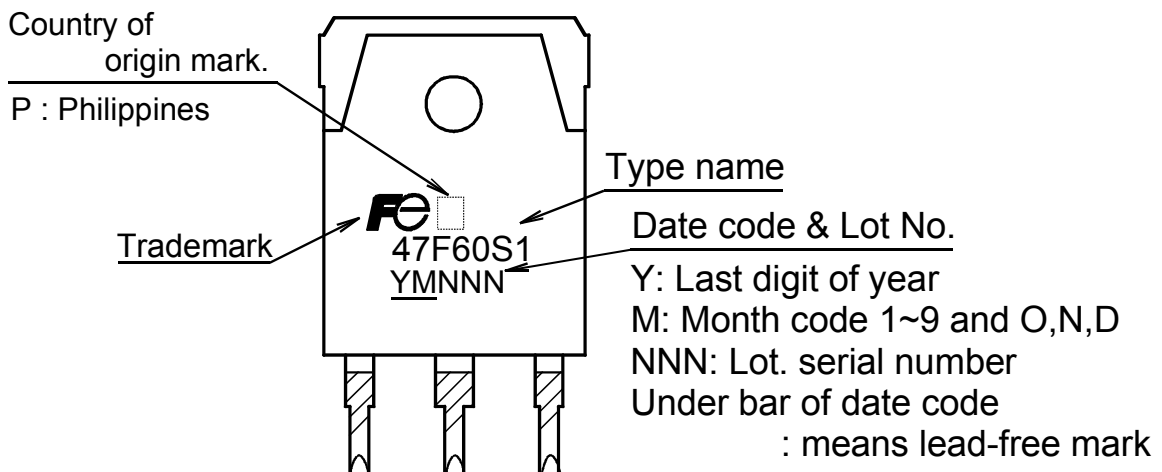
CONNECTION



- ① GATE
- ② DRAIN
- ③ SOURCE

JEDEC : TO-3P  
DIMENSIONS ARE IN MILLIMETERS.

■ Marking



\* The font (font type,size) and the trademark-size might be actually different.

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  - Safety devices
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